

HD74LV1GW06A

Dual Inverter Open Drain

REJ03D0075-0300 Rev.3.00 Sep 08, 2006

Description

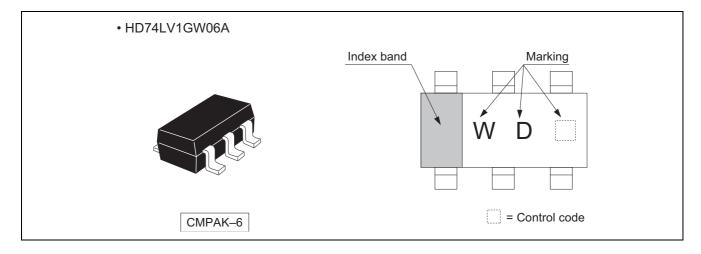
The HD74LV1GW06A has dual inverter open drain in a 6 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range: 1.65 to 5.5 V
- Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- All outputs V_0 (Max.) = 5.5 V (@V_{CC} = 0 V, Output: Z)
- Output current 6 mA (@ $V_{CC} = 3.0 \text{ V}$ to 3.6 V), 12 mA (@ $V_{CC} = 4.5 \text{ V}$ to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV1GW06ACME	CMPAK-6 pin	PTSP0006JA-A (CMPAK-6V)	СМ	E (3,000 pcs / Reel)

Outline and Article Indication



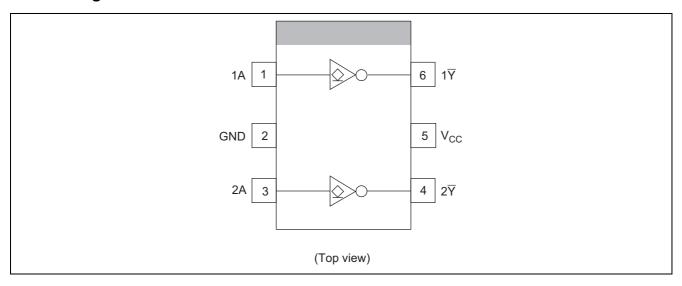
Function Table

Input A	Output ₹
Н	L
L	Z

H : High level L : Low level

Z: High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	Vcc	-0.5 to 7.0	V	
Input voltage range *1	Vı	-0.5 to 7.0	V	
Output voltage range *1, 2	Vo	-0.5 to V _{CC} + 0.5	V	Output : L
Output voltage range	v _o	-0.5 to 7.0	V	V _{CC} : OFF or Output : Z
Input clamp current	I _{IK}	-20	mA	V _I < 0
Output clamp current	lok	-50	mA	V _O < 0
Continuous output current	lo	±25	mA	$V_O = 0$ to V_{CC}
Continuous current through Vcc or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	1.65	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	
Output ourrant		_	1		$V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$
	I _{OL}	_	2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
Output current		_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
		0	300		$V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$
Input transition rise or fall rate	Δt / Δν	0	200	ns / V	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
imput transition rise or fail rate	Δι/Δν	0	100	115 / V	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

 $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V) *1	Min	Тур	Max	Unit	Test Condition
		1.65 to 1.95	V _{CC} ×0.75	_	_		
	\/	2.3 to 2.7	V _{CC} ×0.7	_	_		
	V _{IH}	3.0 to 3.6	V _{CC} ×0.7		_		
Input voltage		4.5 to 5.5	V _{CC} ×0.7	_	_	V	
Input voltage		1.65 to 1.95	_	_	V _{CC} ×0.25	V	
	V_{IL}	2.3 to 2.7	_	_	V _{CC} ×0.3		
	VIL	3.0 to 3.6	_	_	V _{CC} ×0.3		
		4.5 to 5.5	_	_	V _{CC} ×0.3		
		1.8	_	0.25	_		
Hysteresis voltage	V _H	2.5	_	0.30	_	V	$V_T^+ - V_T^-$
		3.3	_	0.35	_	V	ν _Τ – ν _Τ
		5.0	_	0.45	_		
		Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		1.65	_	_	0.3	1	I _{OL} = 1 mA
Output voltage	V_{OL}	2.3	_	_	0.4	V	I _{OL} = 2 mA
		3.0	_	_	0.44		$I_{OL} = 6 \text{ mA}$
		4.5	_	_	0.55		I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state output current	l _{OZ}	Min to Max	_	_	±5	μΑ	V _O = 5.5 V or GND
Quiescent supply current	I _{CC}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I _{OFF}	0	_	_	5	μΑ	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	C _{IN}	3.3	_	3.0	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC}=1.8\pm0.15\ V$

Item	Symbol		Га = 25°C	;	Ta = -40	to 85°C	Unit	Test	FROM	ТО
item	Syllibol	Min	Тур	Max	Min	Max	Oilit	Conditions	(Input)	(Output)
Propagation	t _{ZL}		12.6	22.0	1.0	24.0	no	$C_L = 15 pF$	۸	⊽
delay time	t_{LZ}		19.7	33.0	1.0	36.0	ns	C _L = 50 pF	A	ī

 $V_{CC}=2.5\pm0.2\ V$

Item	Symbol Ta = 25°C		;	Ta = -40	to 85°C	Unit	Test	FROM	ТО	
itein	Syllibol	Min	Тур	Max	Min	Max	Offic	Conditions	(Input)	(Output)
Propagation	t _{ZL}	_	7.0	11.7	1.0	14.0	nc	$C_L = 15 pF$	۸	⊽
delay time	t_{LZ}	_	10.5	15.5	1.0	18.0	ns	$C_L = 50 pF$	A	ı

 $V_{CC}=3.3\pm0.3\ V$

Item	Symbol	7	Га = 25°C	;	Ta = -40) to 85°C	Unit	Test	FROM	ТО
iteiii	Syllibol	Min	Тур	Max	Min	Max	Oilit	Conditions	(Input)	(Output)
Propagation	t _{ZL}		5.0	7.1	1.0	8.5	ne	$C_L = 15 pF$	۸	⊽
delay time	t_{LZ}	_	7.5	10.6	1.0	12.0	ns	C _L = 50 pF	, A	ſ

 $V_{CC}=5.0\pm0.5~V$

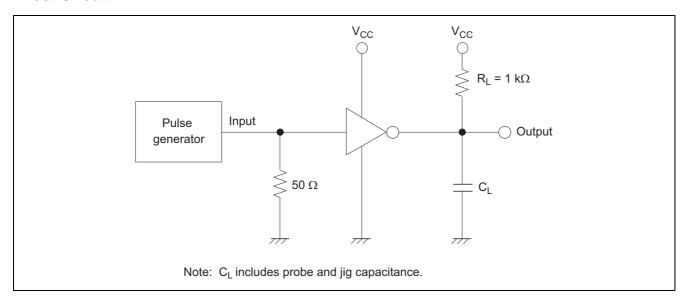
Item	Symbol Ta = 25°C		Ta = -40) to 85°C	Unit	Test	FROM	ТО		
itein	Syllibol	Min	Тур	Max	Min	Max	Oilit	Conditions	(Input)	(Output)
Propagation	t _{ZL}	_	3.8	5.5	1.0	6.5	ne	C _L = 15 pF	۸	⊽
delay time	t_{LZ}	_	5.3	7.5	1.0	8.5	ns	C _L = 50 pF	A	1

Operating Characteristics

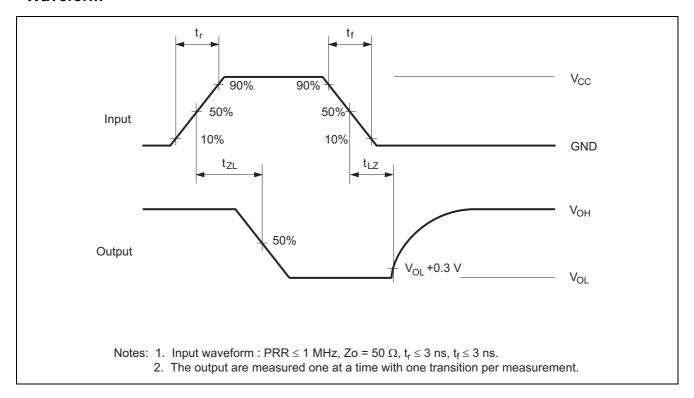
 $C_L = 50 \text{ pF}$

Item	Symbol	V (\(\)	-	Га = 25°C	;	Unit	Test Conditions
		V _{CC} (V)	Min	Тур	Max	Unit	rest conditions
Power dissipation	C	3.3	_	8.5	_	pF	f = 10 MHz
capacitance	C _{PD}	5.0	_	10.0	_	рг	= 10 WI 2

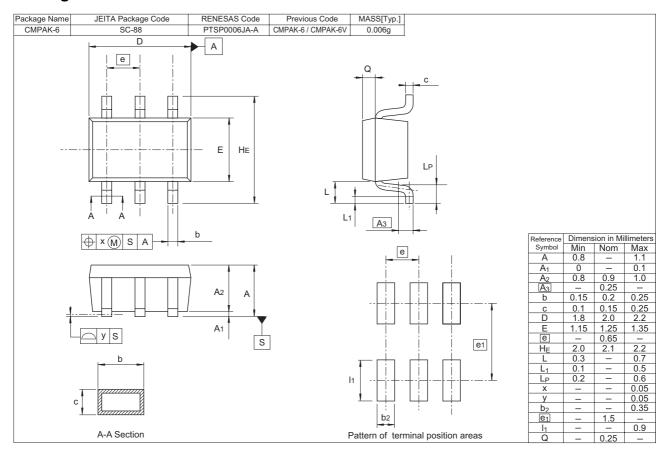
Test Circuit



Waveform



Package Dimensions



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Renesas Technology Hong Kong Ltd.
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Renesas Technology Singapore Pte. Ltd.
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Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

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